HM0225-05A



Product Features

ApplicationsRadio System



- · GaN on SiC HEMT
- 2-stage, In/Out 50Ω Impedance Matching
- Surface Mount Hybrid Type
- Compact Size & Weight
- High Efficiency
- Low Cost
- Custom design available

BEALC HNOZZSIOSA WZZSIO

Package Type: NP-1A

Description

HM0225-05A have a high performance from $200\sim2500MHz$. It has developed for SDR (Software Defined Radio) and TRS (Trunked Radio Service) applications. Using metal-Lid and AlN-board, it's effective for thermal problems. This HM0225-05A is designed using Pout of 5W under Pin of 6dBm.

Electrical Specifications @ V_{ds1} =+9V , V_{ds2} =+24V, V_{gs2} @Idq2, Ta=25 °C

PARAMETER	UNIT	MIN	TYP	MAX	CONDITION
Frequency Range	MHz	200		2500	ZS = ZL = 50 ohm
Output Power	dBm	37	-		
Power Gain	dВ	32	35	-	Amp : Idq1,2 = 180mA
PAE	%	30	-	-	Pout = $37dBm$
Ids2	mA	-	-	700	
IMD	dBc	-21	-25	-	Pout=31dBm (each tone) Two-tone space=1MHz
Input Return Loss (S11)	dB	-5	-10		Idq1,2=180mA
Rising Time of Pout > 90% Falling Time of Pout < 90%	μsec	V. I I	10	CO	Lead and Trail Edge of Drive Bias(+9V) = 10μsec
		-	9	10	Vds1
Supply Voltage	V	-	Vgs2@Idq2	-	Vgs2
		-	24	-	Vds2

Caution

The drain voltage must be supplied to the device after the gate voltage is supplied

Turn on: Turn on the Gate Voltage supply and last turn On the Drain voltage supplies

Turn off: Turn off the Drain Voltage and last turn off the Gate voltage

Note

HM Series have internal DC blocking capacitors at the RF input and output ports



Mechanical Specifications

PARAMETER	UNIT	ТҮР	REMARK
Mass	g	2	-
Dimension	mm	21.1 x 10.6 x 2.5	Outermost

Absolute Maximum Ratings

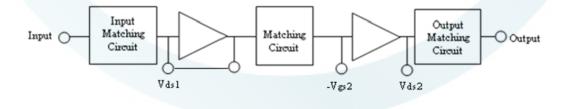
PARAMETER	UNIT	RATING	SYMBOL
Gate-Source Voltage	V	-10 ~ 0	Vgs2
Drain-Source Voltage	V	50	Vds2
Gate Current	mA	3.6	Ig2
Operating Junction Temperature	°C	225	T_{J}
Operating Case Temperature	°C	-40 ~ 85	$T_{\rm C}$
Storage Temperature	°C	- 55 ∼ 100	T_{STG}
Stability into mismatch	-	Stable into VSWR \leq 10:1 (from 100kHz to 8.5GHz at all phase angles at Pin=-30dBm \sim +7dBm and Vds1= 8V \sim 10V and Vds2=12 \sim 24V)	-

Operating Voltages

PARAMETER	UNIT	MIN	ТҮР	MAX	SYMBOL
Drain Voltage 1	V	_	9	10	Vds1
Drain Voltage 2	V	CI	24	28	Vds 2
Gate Voltage 2 (on-state)	V	rtn	Vgs2@Idq2	-1.5	Vgs 2
** Gate Voltage 2 (off-state)	V		-5		Vgs 2

^{**} Gate Voltage 2 (off-state) condition is defined without any RF signal at the input (pin #1).

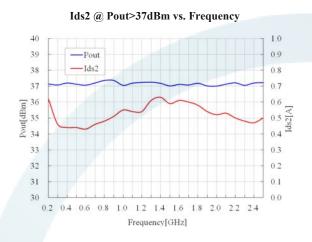
Block Diagram

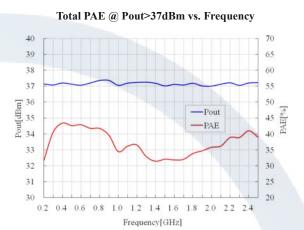




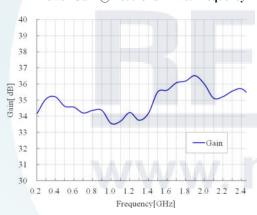
Performance Charts

* **Bias condition** @ Idq1=180mA, Vds1=+9V, Idq2=180mA, Vgs2@Idq2, Vds2 =+24V, Ta=25 °C

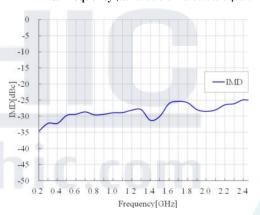




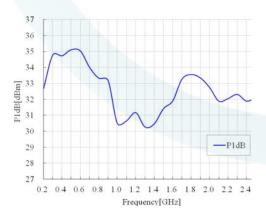
Power Gain @ Pout>37dBm vs. Frequency



IMD vs. Frequency (each-tone of 31dBm and two-tone space of 1MHz)

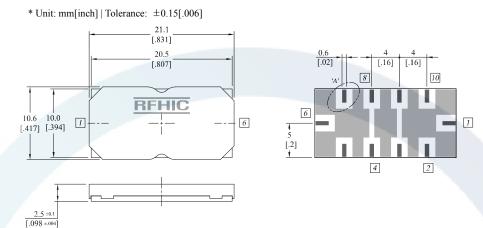


P1dB vs. Frequency





Package Dimensions (Type: NP-1A)

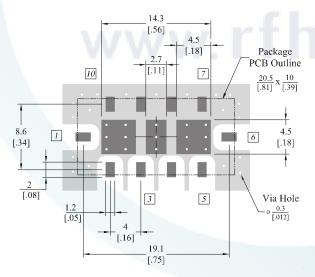


▲ Top & Side View

▲ Bottom View

Pin Description							
Pin No	Function	Pin No	Function	Pin No	Function		
1	Input	5	Vds2	9	GND		
2	Vds1	6	Output	10	GND		
3	Floating	7	GND	-	-		
4	-Vgs2	8	GND	-	-		

Recommended Pattern



* Mounting Configuration Notes

- 1. For the proper performance of the device, Ground / Thermal via holes must be designed to remove heat.
- 2. To properly use heatsink, ensure the ground/thermal via hole region to contact the heatsink. We recommend the mounting screws be added near the heatsink to mount the board
- 3. In designing the necessary RF trace, width will depend upon the PCB material and construction.
- 4. Use 1 oz. Copper minimum thickness for the heatsink.
- 5. Do not put solder mask on the backside of the PCB in the region where the board contacts the heatsink
- 6. We recommend adding as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.



Precautions

This product is a Gallium Nitride Transistor.

The Gallium Nitride Transistor requires a Negative Voltage Bias which operates alongside a Positive Voltage Bias. These Biases are applied in accordance to the Sequence during Turn-On and Turn-Off.

The Pallet Amplifier does not have a built-in Bias Sequence Circuit. Therefore, users need to either apply positive voltages and negative voltages in the required sequence, or add an external Bias Circuit to this Amplifier.

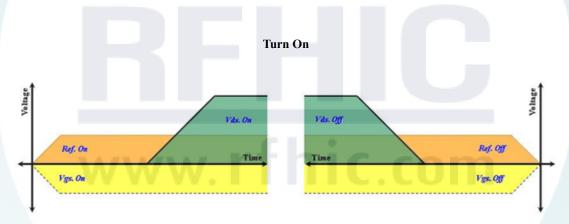
The required sequence for power supply is as follows.

During Turn-On

- 1. Connect GND.
- 2. Apply Vgs2.
- 3. Apply Vds1 and Vds2.
- 4. Apply the RF Power.

During Turn-Off

- 1. Turn off RF power.
- 2. Turn off Vds1 and Vds2, and then, turn off the Vgs2.
- 3. Remove all connections.



- Sequence Timing Diagram -

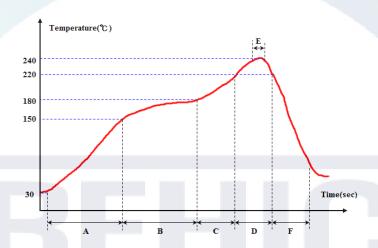


Reflow Profile

* Reflow oven settings

Zone	A	В	C	D	E	F
Temperature(°C)	30 ~ 150 ℃	150 ~ 180 ℃	180 ~ 220 ℃	220 ~ 220 ℃	235 ~ 240 ℃	$2 \sim 6$ °C/Sec Drop
Belt speed	55 ~ 115 sec	55 ~ 75 sec	30 ~ 50 sec	30 ~ 50 sec	5 ~ 10 sec	60 ~ 90 sec

* Measured reflow profile



Ordering Information

Part Number	Package Design		
	-R (Reel)		
HM0225-05A	-B (Bulk)		
VV VV VV . I I	-EVB (Evaluation Board)		

Revision History

Part Number	Release Date	Version	Modification	Data Sheet Status
HM0225-05A	2016.02.03	1.3	Ids2 max. range of Electric Specifications	-
HM0225-05A	2014.01.20	1.2	Vgs(on-stage) of 'Operating Voltages' is changed to '-1.5V'.	-
HM0225-05A	2013.11.01	1.1	Storage temperature is changed to '-55°C' and 'Stability into mismatch' is added to 'Absolute Maximum Ratings'.	-

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